#### Notification about the transfer of the semiconductor business

The semiconductor business of Panasonic Corporation was transferred on September 1, 2020 to Nuvoton Technology Corporation (hereinafter referred to as "Nuvoton"). Accordingly, Panasonic Semiconductor Solutions Co., Ltd. became under the umbrella of the Nuvoton Group, with the new name of Nuvoton Technology Corporation Japan (hereinafter referred to as "NTCJ").

In accordance with this transfer, semiconductor products will be handled as NTCJ-made products after September 1, 2020. However, such products will be continuously sold through Panasonic Corporation.

Publisher of this Document is NTCJ.

If you would find description "Panasonic" or "Panasonic semiconductor solutions", please replace it with NTCJ.

Except below description page
 "Request for your special attention and precautions in using the technical information and semiconductors described in this book"

Nuvoton Technology Corporation Japan

Doc No. TT4-EA-14179

Revision. 2

# **Panasonic**

MOS FET

### MTM231102LBF

### MTM231102LBF

#### Silicon P-channel MOSFET

### For Switching

#### MTM76110 in SMini3 type package

#### ■ Features

- Low Drain-source On-state Resistance : RDS(on) typ. = 30 m $\Omega$  (VGS = -4 V)
- Low Drive Voltage: 1.8 V Drive
- Halogen-free / RoHS compliant

(EU RoHS / UL-94 V-0 / MSL : Level 1 compliant)

■ Marking Symbol : DM

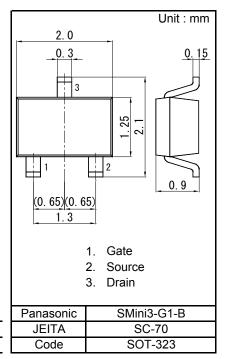
#### ■ Packaging

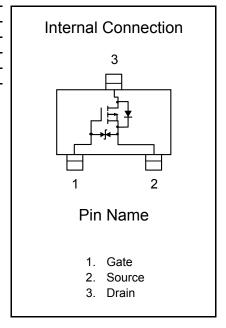
Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

	_			
Parameter	Symbol	Rating	Unit	
Drain to Source Voltage	VDS	-12	V	
Gate to Source Voltage	VGS	±8	V	
Drain Current	ID	-4	Α	
Drain Current (Pulsed) *1	IDp	-16	Α	
Total Power Dissipation *2	PD	500	mW	
Channel Temperature	Tch	150	°C	
Storage Temperature Range	Tstg	-55 to +150	°C	

Note \*1 Pulse width = 10  $\mu s$ , Duty cycle  $\leq$  1 %





 $<sup>^{*}2</sup>$  Measuring on ceramic board at 40 mm  $\times$  38 mm  $\times$  0.1 mm. Absolute maximum rating PD Non-heat sink shall be made 150 mW.

Doc No. TT4-EA-14179 Revision. 2

# **Panasonic**

MOS FET MTM231102LBF

#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

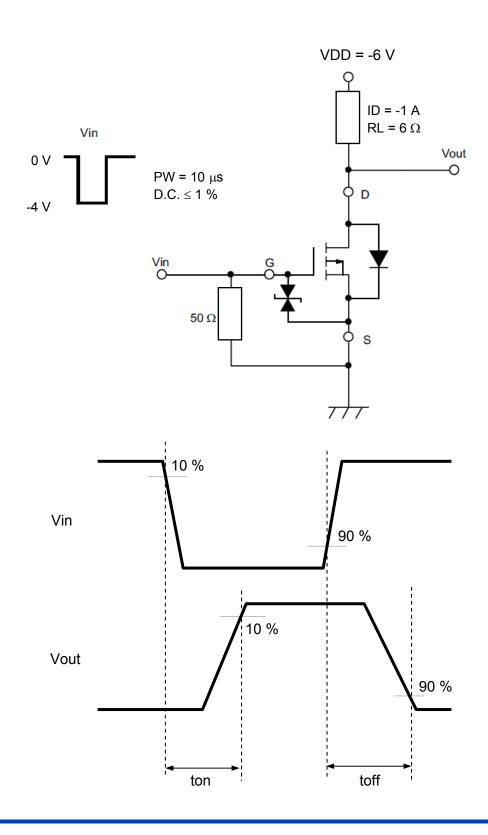
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source Breakdown Voltage	VDSS	ID = -1 mA, VGS = 0 V	-12			V
Zero Gate Voltage Drain Current	IDSS	VDS = -12 V, VGS = 0 V			-1	μΑ
Gate-source Leakage Current	IGSS	VGS = $\pm 6.4 \text{ V}$ , VDS = 0 V			±10	μΑ
Gate-source Threshold Voltage	Vth	ID = -1 mA, VDS = -6 V	-0.3	-0.65	-1	V
Drain-source On-state Resistance *1	RDS(on)1	ID = -1 A, VGS = -4 V		30	40	mΩ
	RDS(on)2	ID = -0.5 A, VGS = -2.5 V		35	55	
	RDS(on)3	ID = -0.2 A, VGS = -1.8 V		50	75	
Forward transfer admittance *1	Yfs	ID = -1 A, VDS = -10 V, f = 1 kHz	3.5			S
Input Capacitance	Ciss	VDS = -10 V, VGS = 0 V		1 200		pF
Output Capacitance	Coss	f = 1 MHz		110		
Reverse Transfer Capacitance	Crss	1 - 1 MHZ		110		
Turn-on Delay Time *2	ton	VDD = -6 V, VGS = 0 to -4 V		25		no
Rise Time *2	ton	ID = -1 A		25		ns
Turn-off Delay Time *2	toff	VDD = -6 V, VGS = -4 to 0 V		300		no
Fall Time *2		ID = -1 A		300		ns

Note: Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

<sup>\*1</sup> Pulse test : Pulse width  $\leq$  10  $\mu$ s, Duty cycle  $\leq$  1 %

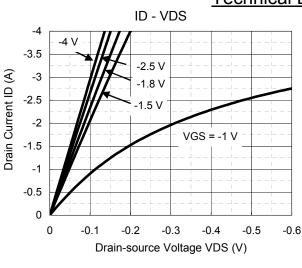
<sup>\*2</sup> Measurement circuit for Turn-on Delay Time / Turn-off Delay Time

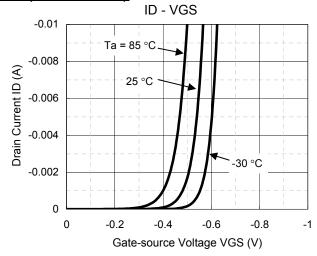
\*2 Measurement circuit for Turn-on Delay Time / Turn-off Delay Time

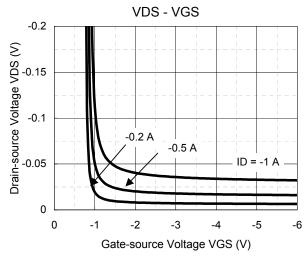


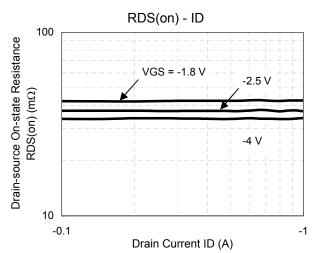
MOS FET MTM231102LBF

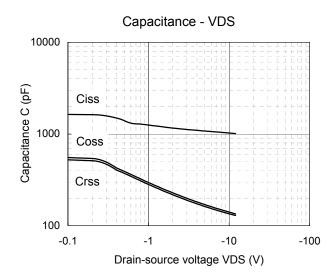
## Technical Data (reference)





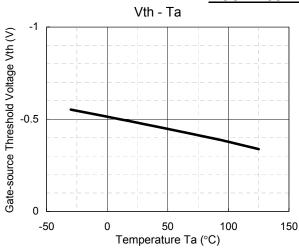


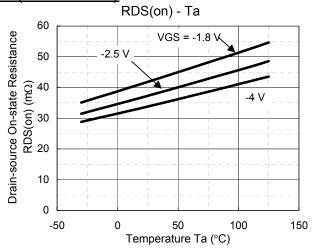


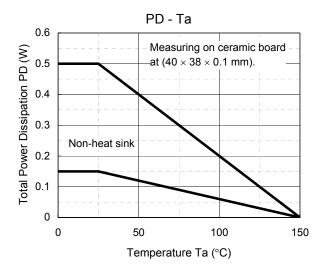


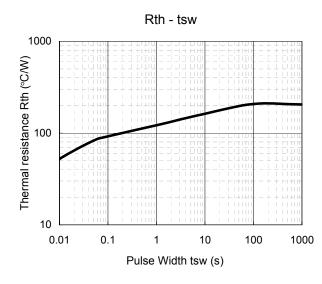
MOS FET MTM231102LBF

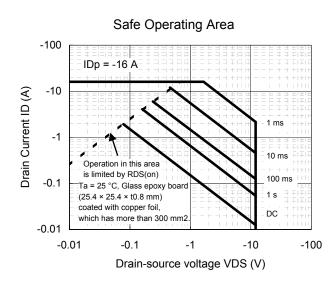
## Technical Data (reference)









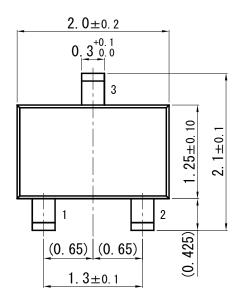


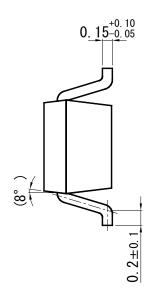
# MOS FET

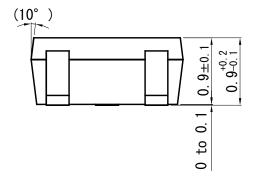
## MTM231102LBF

SMini3-G1-B

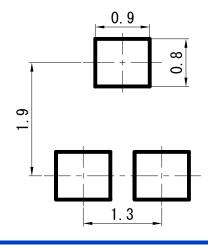
Unit: mm







■ Land Pattern (Reference) (Unit : mm)



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